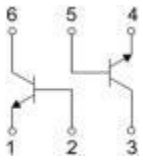
SOT-563



MARKING:KAP

FEATURE

Epitaxial planar die construction

Ideal for low power amplification and switching

MAXIMUM RATINGS (T_a=25℃ unless otherwise noted)

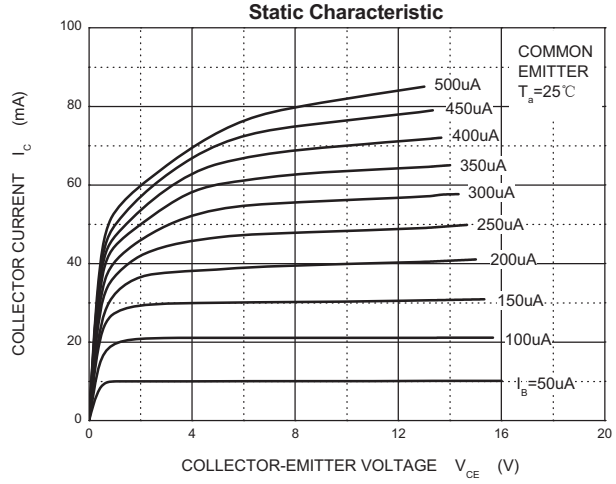
Symbol	parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	60	V
V_{CEO}	Collector-Emitter Voltage	40	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current -Continuous	0.2	A
p_C	Collector Power Dissipation	0.2	W
T_J,T_{stg}	Operation Junction and Storage Temperature Range	-55~+150	℃

ELECTRICAL CHARACTERISTICS (Ta=25℃ unless otherwise specified)

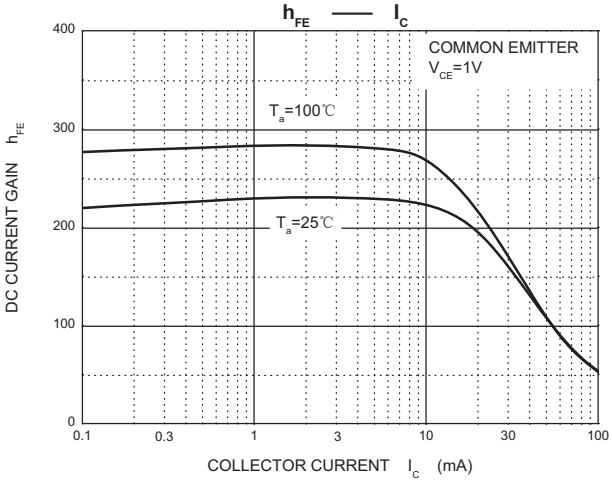
parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown Voltage	$V_{(BR)CBO}$	I_C=10μA,I_E=0	60			V
Collector-emitter breakdown Voltage	$V_{(BR)CEO}$	I_C=1mA,I_B=0	40			V
Emitter-base breakdown Voltage	$V_{(BR)EBO}$	I_E=10μA,I_C=0	5			V
Collector cut-off current	I_{CBO}	V_{CB}=30V,I_E=0			0.05	μA
Emitter cut-off current	I_{EBO}	V_{EB}=5V,I_C=0			0.05	μA
Collector cut-off current	I_{CEX}	V_{CE}=30V,$V_{BE(off)}$=3V			0.05	μA
DC current gain	$h_{FE(1)}$	V_{CE}=1V,I_C=0.1mA	40			
	$h_{FE(2)}$	V_{CE}=1V,I_C=1mA	70			
	$h_{FE(3)}$	V_{CE}=1V,I_C=10mA	100		300	
	$h_{FE(4)}$	V_{CE}=1V,I_C=50mA	60			
	$h_{FE(5)}$	V_{CE}=1V,I_C=100mA	30			
Collector-emitter saturation Voltage	$V_{CE(sat)1}$	I_C=10mA,I_B=1mA			0.2	V
	$V_{CE(sat)2}$	I_C=50mA,I_B=5mA			0.3	V
Base-emitter saturation Voltage	$V_{BE(sat)1}$	I_C=10mA,I_B=1mA	0.65		0.85	V
	$V_{BE(sat)2}$	I_C=50mA,I_B=5mA			0.95	V
Transition frequency	f_T	V_{CE}=20V,I_C=10mA,f=100MHz	300			MHz
Collector output capacitance	C_{ob}	V_{CB}=5V,I_E=0,f=1MHz			4	pF
Delay time	td	V_{CC}=3V, $V_{BE(off)}$=-0.5V I_C=10mA , I_{B1}=-I_{B2}= 1mA			35	ns
Rise time	t_r				35	ns
Storage time	t_s	V_{CC}=3V, I_C=10mA I_{B1}=-I_{B2}=1mA			200	ns
Fall time	t_f				50	ns

Typical Characteristics

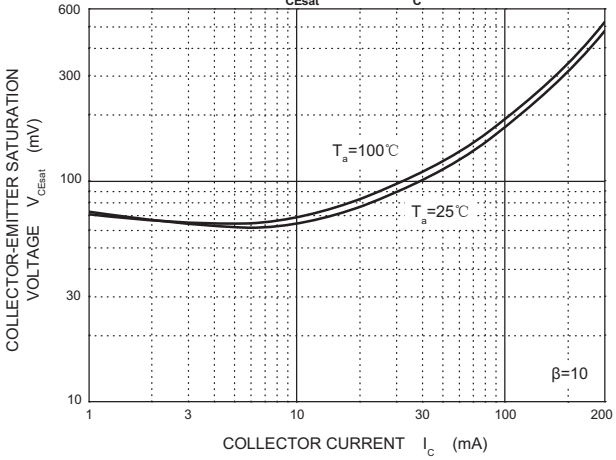
Static Characteristic



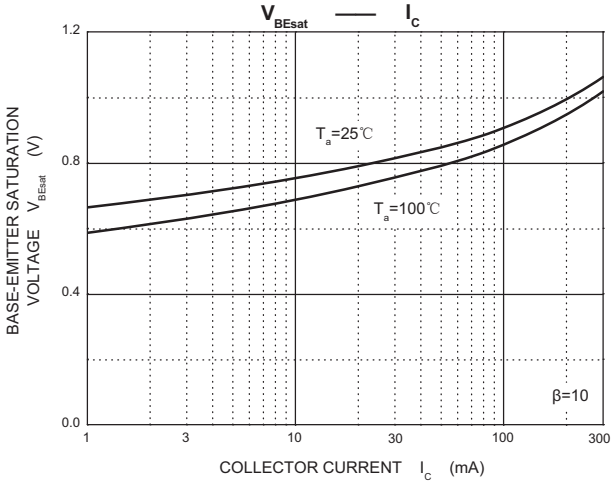
h_{FE} —— I_C



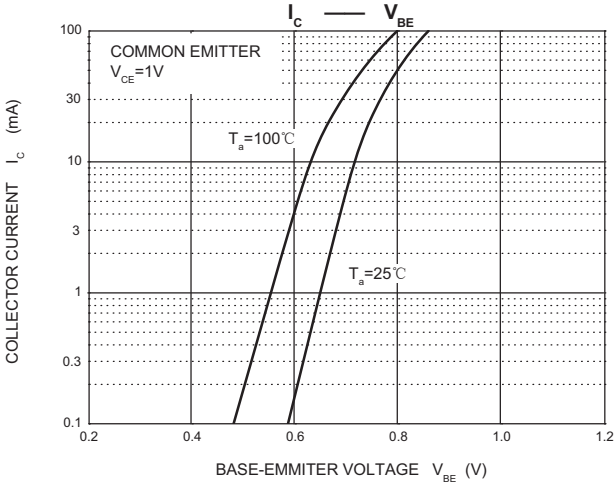
V_{CEsat} —— I_C



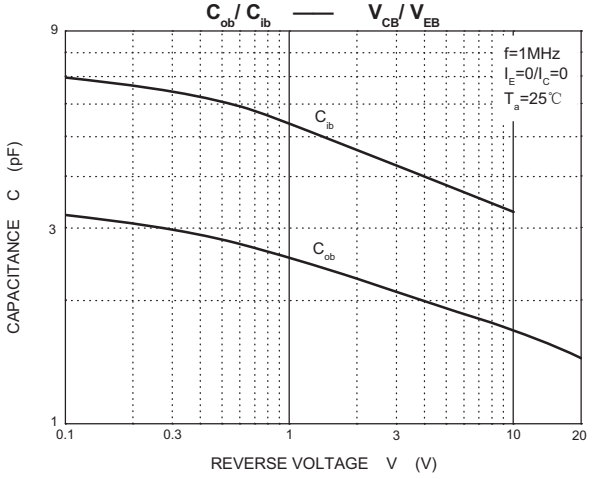
V_{BEsat} —— I_C



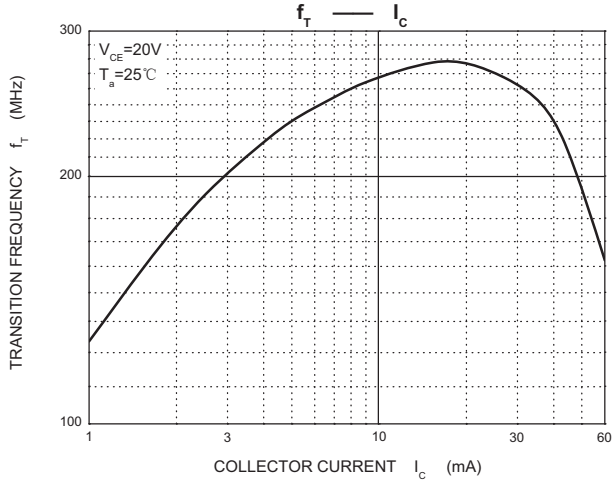
I_C —— V_{BE}



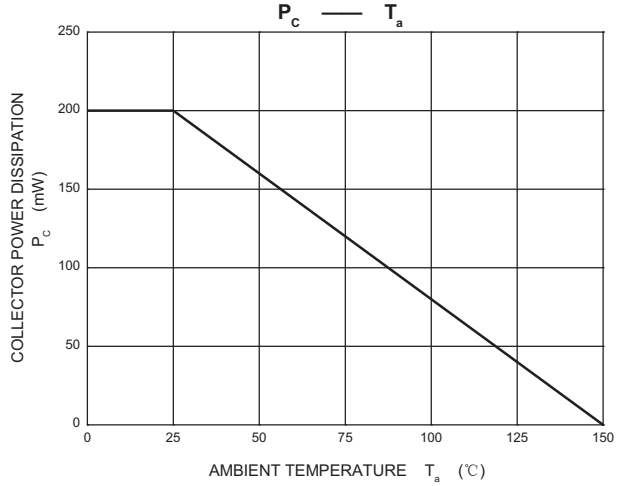
C_{ob} / C_{ib} —— V_{CB} / V_{EB}



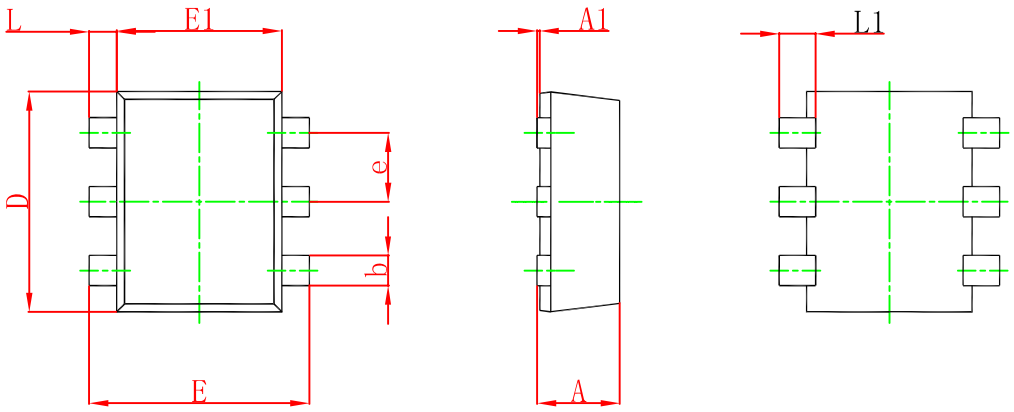
f_T —— I_C

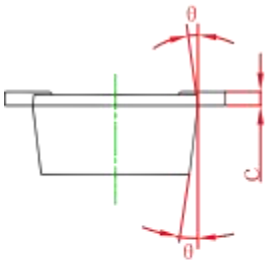


P_C —— T_a



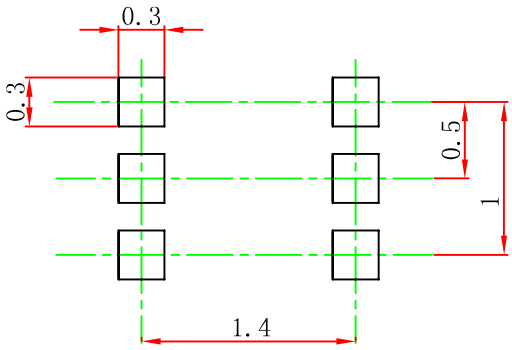
SOT-563 Package Outline Dimensions





Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.525	0.600	0.021	0.024
A1	0.000	0.050	0.000	0.002
e	0.450	0.550	0.018	0.022
c	0.090	0.160	0.004	0.006
D	1.500	1.700	0.059	0.067
b	0.170	0.270	0.007	0.011
E1	1.100	1.300	0.043	0.051
E	1.500	1.700	0.059	0.067
L	0.100	0.300	0.004	0.012
L1	0.200	0.400	0.008	0.016
θ	10° REF.		10° REF.	

SOT-563 Suggested Pad Layout



Note:
1.Controlling dimension:In millimeters.
2.General tolerance:±0.05mm.
3.The pad layout is for reference purposes only.